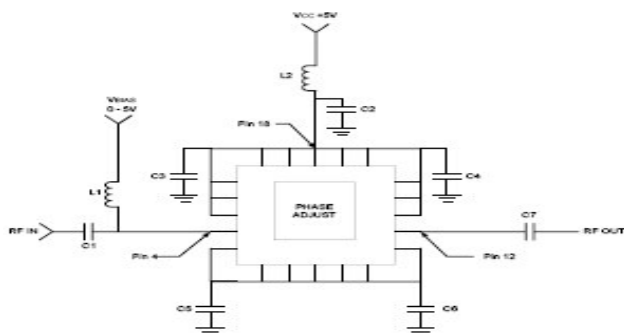




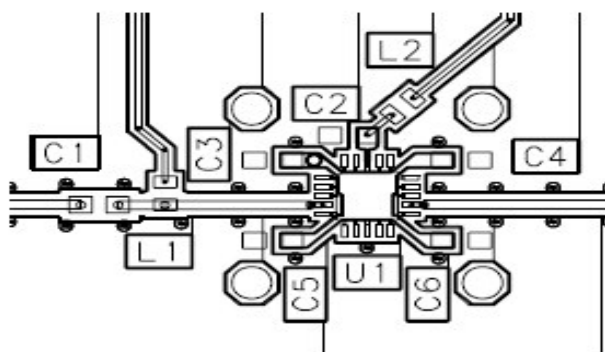
**Voltage Variable Phase Shifter,  
1.85 - 1.99 GHz**

**MACMCC0004  
V3**

**Functional Diagram and Bias Circuitry**



**Recommended PCB Configuration**



1. Circuit Material = FR-4, TETRA II, .010 ± .001 thick.
2. Line Width = 0.018 inches, Line Spacing = 0.016 inches for 50 ohm line.

**Pin Configuration<sup>3</sup>**

Pin No.	Function	Pin No.	Function
1	RF GND, V <sub>CC</sub>	11	RF GND, V <sub>CC</sub>
2	RF GND, V <sub>CC</sub>	12	RF OUT
3	RF GND, V <sub>CC</sub>	13	RF GND, V <sub>CC</sub>
4	RF IN, V <sub>BIAS</sub>	14	RF GND, V <sub>CC</sub>
5	RF GND, V <sub>CC</sub>	15	RF GND, V <sub>CC</sub>
6	RF GND, V <sub>CC</sub>	16	RF GND, V <sub>CC</sub>
7	RF GND, V <sub>CC</sub>	17	RF GND, V <sub>CC</sub>
8	RF GND, V <sub>CC</sub>	18	RF GND, V <sub>CC</sub>
9	RF GND, V <sub>CC</sub>	19	RF GND, V <sub>CC</sub>
10	RF GND, V <sub>CC</sub>	20	RF GND, V <sub>CC</sub>

3. V<sub>CC</sub> is +5 Volts, V<sub>BIAS</sub> is 0 to 5 Volts.

**Absolute Maximum Ratings<sup>5</sup>**

Parameter	Absolute Maximum
Operating Voltage <sup>6,7</sup>	Breakdown Voltage
Operating Temperature	-65°C to +125°C
Storage Temperature	-65°C to +200°C

5. Operation of this device above any one of these parameters may cause permanent damage.
6. Breakdown Voltage = 22 volts minimum, measured at 10 microamps.
7. To operate this device above the recommended V<sub>B</sub> = +5V; increase V<sub>C</sub> to 22 volts maximum.

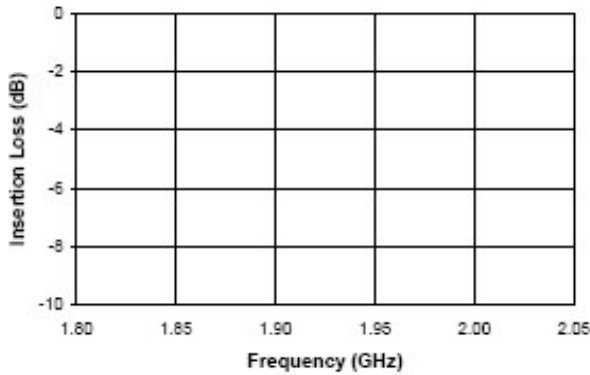
**External Circuitry Parts<sup>8</sup>**

Part	Value	Purpose
C1, C7	100pF	DC Block
C2, C3, C4, C5, C6	22 pF	Capacitors to float RF Ground
L1, L2	33 nH	RF Choke

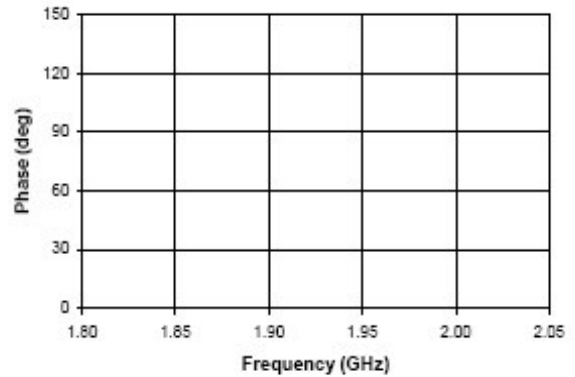
8. All external circuitry parts are readily available, low cost surface mount components (.060 in. x .030 in or .080 in x .050 in.).

**Typical Performance Curves**

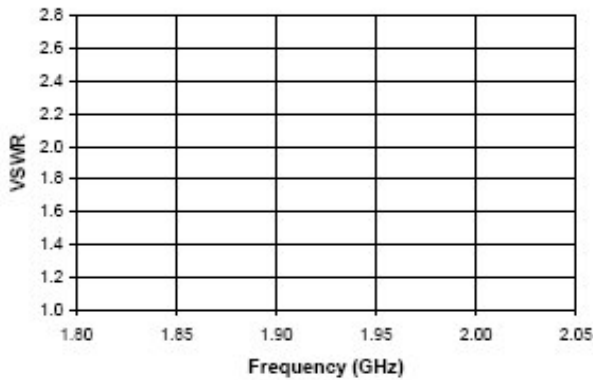
*Insertion Loss*



*Phase*



*Input VSWR*



*Output VSWR*

